

HVD147

Silicon Epitaxial Trench Pin Diode for Antenna Switching

REJ03G0392-0200 Rev.2.00 Oct 20, 2004

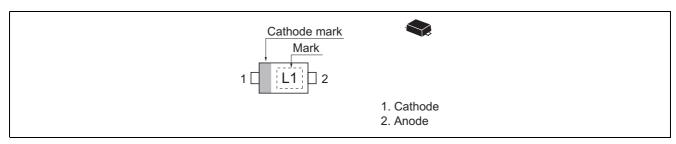
Features

- Adopting the trench structure improves low capacitance. (C = 0.31 pF max)
- Low forward resistance. (rf = $1.5 \Omega \text{ max}$)
- Low operation current.
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVD147	L1	SFP

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Reverse voltage	V_R	30	V
Forward current	I _F	100	mA
Power dissipation	Pd	150	mW
Junction temperature	Тј	125	°C
Storage temperature	Tstg	-55 to +125	°C

Electrical Characteristics

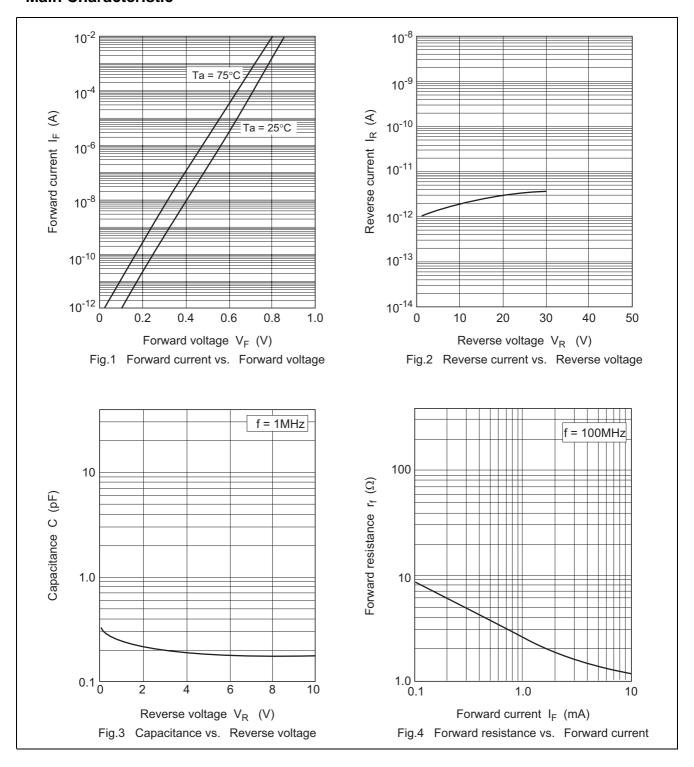
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _R	_	_	100	nA	V _R = 30 V
Forward voltage	V _F	_	_	1.00	V	I _F = 10 mA
Capacitance	С	_	_	0.31	pF	V _R = 1 V, f = 1 MHz
Forward resistance	r _f	_	2.5	_	Ω	I _F = 2 mA, f = 100 MHz
		_	_	1.5		I _F = 10 mA, f = 100 MHz
ESD-Capability *1	_	100	_	_	V	$C = 200 \text{ pF}, R = 0 \Omega$, Both forward
						and reverse direction 1 pulse.

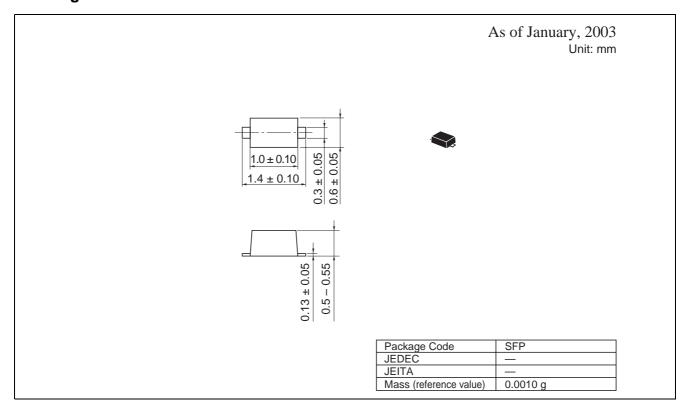
Notes: 1. Failure criterion ; $I_R > 100 \text{ nA}$ at $V_R = 30 \text{ V}$

^{2.} Please do not use the soldering iron due to avoid high stress to the SFP package.

Main Characteristic



Package Dimensions



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